74AHC1G79-Q100; 74AHCT1G79-Q100 Single D-type flip-flop; positive-edge trigger Rev. 1 — 16 May 2013

Product data sheet

1. **General description**

74AHC1G79-Q100 and 74AHCT1G79-Q100 are high-speed Si-gate CMOS devices. They provide a single positive-edge triggered D-type flip-flop.

Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D input must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)



3. Ordering information

Table 1. Ordering information

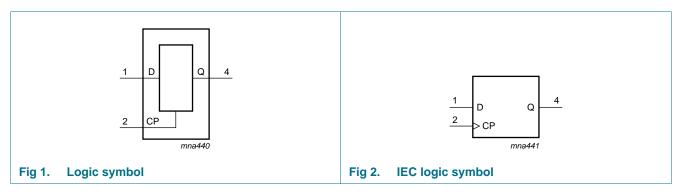
Type number	Package	ackage							
	Temperature range	Name	Description	Version					
74AHC1G79GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads;	SOT353-1					
74AHCT1G79GW-Q100			body width 1.25 mm						
74AHC1G79GV-Q100	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753					
74AHCT1G79GV-Q100									

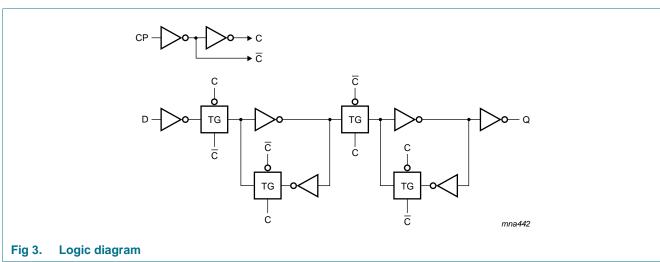
4. Marking

Table 2. Marking codes

Type number	Marking
74AHC1G79GW-Q100	AP
74AHCT1G79GW-Q100	A79
74AHC1G79GV-Q100	СР
74AHCT1G79GV-Q100	C79

5. Functional diagram





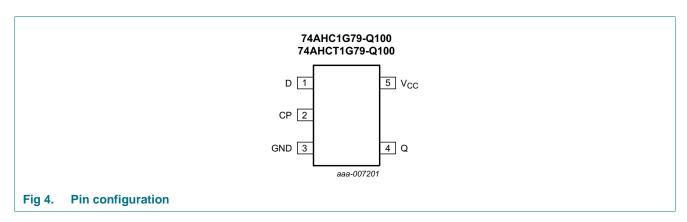
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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

	•		
Symbol	Pin	Description	
D	1	data input	
СР	2	clock pulse input	
GND	3	ground (0 V)	
Q	4	data output	
V_{CC}	5	supply voltage	

7. Functional description

Table 4. Function table[1]

Inputs		Output
СР	D	Q + 1
\uparrow	L	L
\uparrow	Н	Н
L	X	Q

[1] H = HIGH voltage level;

L = LOW voltage level;

↑ = LOW-to-HIGH CP transition;

X = don't care:

Q + 1 = state after the next LOW-to-HIGH CP transition.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V}$	-20	-	mA
I_{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	75	mA
I_{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$	[2] _	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74Al	IC1G79-	Q100	74AH	CT1G79	-Q100	Q100 Unit		
			Min	Тур	Max	Min	Тур	Max			
V_{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V		
V_{I}	input voltage		0	-	5.5	0	-	5.5	V		
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V		
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C		
$\Delta t/\Delta V$	input transition rise	V_{CC} = 3.3 V \pm 0.3 V	-	-	100	-	-	-	ns/V		
	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V		

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions		25 °C			to +85 °C	–40 °C t	Unit	
		Min	Тур	Max	Min	Max	Min	Max		
For type	74AHC1G79-0	2100	'		•					
V_{IH}	V _{IH} HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
		$V_{CC} = 3.0 \text{ V}$	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
input voltage	$V_{CC} = 3.0 \text{ V}$	-	-	0.9	-	0.9	-	0.9	V	
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V

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^[2] For both TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

Single D-type flip-flop; positive-edge trigger

Table 7. Static characteristics ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Ur
			Min	Тур	Max	Min	Max	Min	Max	
√ _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}				•				
	output voltage	$I_O = -50 \mu A$; $V_{CC} = 2.0 \text{ V}$	1.9	2.0	-	1.9	-	1.9	-	٧
		$I_O = -50 \mu A; V_{CC} = 3.0 V$	2.9	3.0	-	2.9	-	2.9	-	٧
		$I_O = -50 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	٧
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	٧
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.70	-	٧
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 50 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 50 \mu A; V_{CC} = 3.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 50 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	٧
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	٧
I _I	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μ
Cı	input capacitance		-	1.5	10	-	10	-	10	pl
For type	74AHCT1G79-	Q100								
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -50 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -8.0 \text{ mA}$	3.94	-	-	3.8	-	3.70	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	٧
		$I_0 = 8.0 \text{ mA}$	-	-	0.36	-	0.44	-	0.55	V
l _l	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μ
Icc	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μ
Δl _{CC}	additional supply current	per input pin; $V_I = 3.4 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 5.5 \text{ V}$	-	-	1.35	-	1.5	-	1.5	m
Cı	input capacitance		-	1.5	10	-	10	-	10	pl

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; $t_f = t_f = \le 3.0$ ns. For test circuit, see <u>Figure 6</u>. For waveforms, see <u>Figure 5</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C 1	o +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
For type	74AHC1G79-	-Q100					'	1	,	'	
t _{pd}	propagation	CP to Q	[1]								
	delay	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]								
		$C_L = 15 pF$		-	4.9	8.4	1.0	9.8	1.0	11.5	ns
		$C_L = 50 pF$		-	6.9	12.0	1.0	14.0	1.0	15.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	[3]								
		$C_L = 15 pF$		-	3.5	5.6	1.0	7.0	1.0	8.0	ns
		$C_L = 50 pF$		-	5.1	8.0	1.0	10.0	1.0	11.0	ns
t _{su}	set-up time	D to CP		3.0	1.0	-	3.0	-	4.0	-	ns
t _h	hold time	D to CP		+2.0	-1.0	-	2.0	-	3.0	-	ns
t_{W}	pulse width	clock HIGH or LOW		3.0	-	-	3.0	-	4.0	-	ns
f _{max}	maximum frequency			90	-	-	90	-	70	-	MHz
C _{PD}	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	15	-	-	-	-	-	pF
For type	74AHCT1G7	9-Q100									
t _{pd}	propagation	CP to Q	[1]								
	delay	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	[3]								
		$C_{L} = 15 pF$		-	3.5	5.0	1.0	6.0	1.0	8.0	ns
		$C_L = 50 pF$		-	5.0	8.0	1.0	10.0	1.0	11.0	ns
t _{su}	set-up time	D to CP		3.0	1.0	-	3.0	-	4.0	-	ns
t _h	hold time	D to CP		+2.0	-1.0	-	2.0	-	3.0	-	ns
t _W	pulse width	clock HIGH or LOW		3.0	-	-	3.0	-	4.0	-	ns
f _{max}	maximum frequency			90	-	-	90	-	70	-	MHz
C _{PD}	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	16	-	-	-	-	-	pF

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

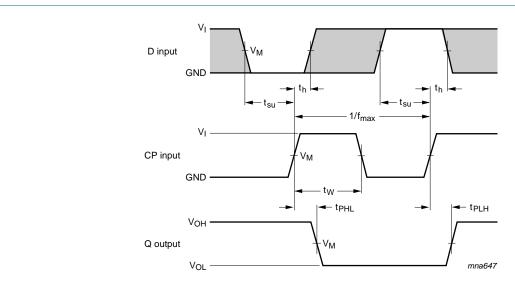
 V_{CC} = supply voltage in Volts.

^[2] Typical values are measured at $V_{CC} = 3.3 \text{ V}$.

^[3] Typical values are measured at $V_{CC} = 5.0 \text{ V}$.

^[4] C_{PD} is used to determine the dynamic power dissipation P_D (μW).

12. Waveforms



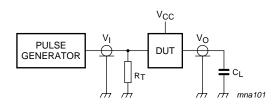
Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output.

Fig 5. Clock (CP) to output (Q) propagation delay times, clock pulse width, D to set-up times, the CP to D hold times and maximum clock pulse frequency

Table 9. Measurement points

Туре	Inputs	nputs		
	V _I	V _M	V _M	
74AHC1G79-Q100	GND to V _{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	
74AHCT1G79-Q100	GND to 3.0 V	1.5 V	$0.5 \times V_{CC}$	



Test data is given in <u>Table 8</u>. Definitions for test circuit:

 C_L = Load capacitance including jig and probe capacitance.

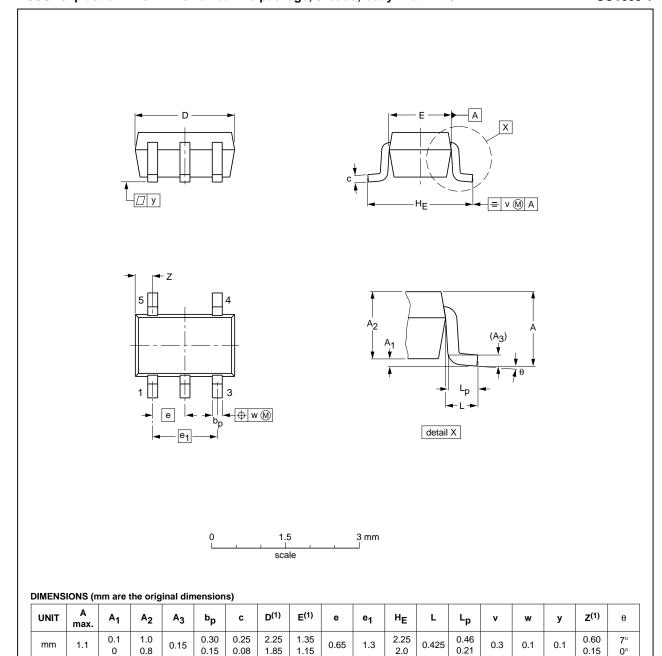
 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

Fig 6. Test circuit for measuring switching times

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



Nata

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	VEDSION					ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			-00-09-01 03-02-19

Fig 7. Package outline SOT353-1 (TSSOP5)

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Plastic surface-mounted package; 5 leads

SOT753

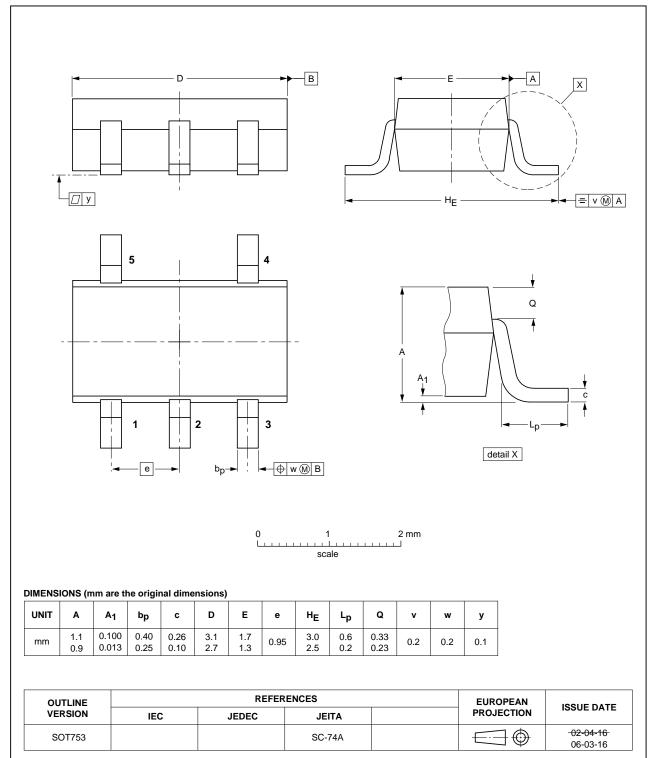


Fig 8. Package outline SOT753 (SC-74A)

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Single D-type flip-flop; positive-edge trigger

14. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic
MIL	Military

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT1G79_Q100	20130516	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Single D-type flip-flop; positive-edge trigger

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Single D-type flip-flop; positive-edge trigger

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